## Mapping residual stress profiles at the micron scale using FIB microhole drilling

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Abstract. Measuring residual stress at the sub-micron scale imposes experimental challenges. We propose a new technique, namely the incremental micro-hole-drilling method (I $\mu$ HM), for measurement of residual stress profiles as a function of depth with high spatial definition. Like its macroscale counterpart, it is applicable to either crystalline or amorphous materials, but at the sub-micron scale. Our method involves micro-hole milling using the focused ion beam of a dual beam FEGSEM/FIB microscope. The surface displacements are tracked by digital image correlation of SEM images recorded during milling. The displacement fields mapped around the whole are used to reconstruct the variation of the in-plane stress tensor as a function of depth. In this way the multi-axial state of residual stress has been characterised around drilled holes of 2 microns. Here we demonstrate the efficacy of this method by measuring the stresses in a surface-severe-plastically-deformed (S<sup>2</sup>PD) Zr<sub>50</sub>Cu<sub>40</sub>Al<sub>10</sub> bulk metallic glass (in atomic percent, at.%) sample after failure under four-point-bending-fatigue.

## Introduction

Residual stresses exist in most materials across a range of scales [1, 2]. They arise as a consequence of prior processing and/or in-service loading. Reliable information about the state of residual stress in a component or structure is often an essential part of the structural integrity assessment. At the macro scale the Incremental Hole Drilling Method [3-6] is a well established semi-destructive method for measurement of non-uniform residual stresses near the surface of a component. In essence, the method involves drilling a small shallow hole to a depth not greater than its diameter (a few millimetres say) in the specimen. The strain introduced by the partial relaxation of the stress around the hole is recorded by a strain gauge rosette stepwise over a series of drilling increments. Subsequently, the residual stress profiles are back-calculated using the Integral Method [4, 5] based on calibration data calculated by finite elements. The tendency for unstable residual stress solutions to the Integral Method, when small increments of hole-depth are selected either at very shallow or at depths approaching the hole diameter, is countered by a Tikhonov regularization scheme [7].

Destructive and semi-destructive techniques based on mechanical relaxation phenomena, such as hole/core drilling [4, 5, 8], slitting [9], and curvature methods [10] can be applied to both crystalline and amorphous materials. In principle they can be scaled down and applied to smaller structures than those to which they have been applied to-date. The advent of dual beam focused ion beam – field emission gun scanning electron microscopes (FIB-FEGSEM) in combination with digital image correlation analysis (DIC) has made it possible to make very fine holes or excisions and to record the resulting displacements with high precision. This has recently led to a number of microscale analogues of the mechanical stress measurement methods, principally using cantilevers or slots [11-15]. The disadvantage of these techniques is that they tend to measure one component of the in-plane stress tensor and have relatively poor lateral spatial resolution (tens of micros).

In this paper we outline the measurement principle of a new FIB micro-hole drilling method based on the Incremental Hole Drilling Method [4, 5]. We adopt a Tikhonov regularization scheme

[7] to stabilise the reconstructed residual stress profiles ( $\sigma_x$ ,  $\sigma_y$  and  $\tau_{xy}$ ). Here this new method is used to drill a 4 µm hole to estimate the residual-stresses tensor with a depth resolution of ~200 nm and a lateral resolution of around 10 µm in a surface-severe-plastically-deformed (S<sup>2</sup>PD) Zr<sub>50</sub>Cu<sub>40</sub>Al<sub>10</sub> BMG (in at.%) system after failure under four-point-bending-fatigue [15].

## **Experimental Description**

**Material preparation.** Zr, Cu and Al melts<sup>†</sup> were argon arc-melted and tilt-casted to obtain  $Zr_{50} Cu_{40} Al_{10}$  (atm%) BMG. Then one side of the specimen was argon shot-peened with WC/Co shots. Later the fatigue behaviour of the BMG was studied under four-point-bending-fatigue [15].

**Surface Contrast Enhancement for DIC.** The reliability of the DIC analysis and the scalability of the FIB-based hole drilling method strongly depend on the size, distribution, and density of the surface features that are tracked [16]. Here we have decorated the specimen surface with 20 to 30 nm equiaxed yttria-stabilized zirconia (YSZ) particles (~13% coverage) precipitated from an ethanol suspension (see Fig. 1a). We used an ultrasonic bath to break up large YSZ particle conglomerates in the suspension prior to application. To minimise surface charging and to 'protect' the surface from Ga<sup>+</sup> implantation, the surface of the specimen is coated with a carbon film of 220 Å thickness using a Gatan PECS 682 etching-coating system equipped with a Gatan 681.20000 Film Thickness Monitor.

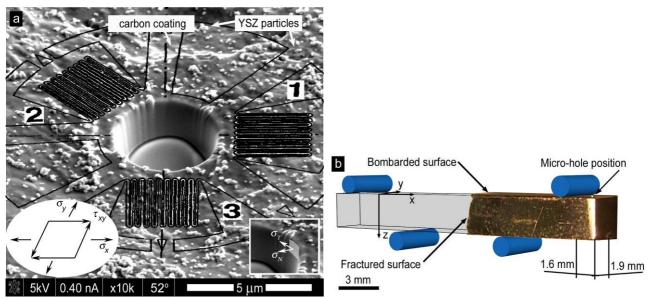


Figure 1. FEGSEM image of the microhole of radius  $r_a = 4 \pm 0.07 \,\mu\text{m}$  and depth,  $z = 1.8 \pm 0.07 \,\mu\text{m}$ : (a) showing the micro-hole at an oblique viewing angle with superimposed virtual strain-gauge rosette  $r_a/r = 0.50$ , where r is the radius of strain-gauge rosette; the surface is decorated with YSZ nano-particles and then carbon coated (the film thickness is about 20 nm); (b) general view showing fatigue test configuration and location of the micro-hole.

FIB Micro-hole Drilling. In order to map the stress profile in a severely plastically peen deformed BMG at the location shown in Fig. 1b, we have introduced a micro-hole of  $2 \mu m$  radius to a depth of 1.8  $\mu m$  (see Fig. 1a) in 11 increments using FEI Dual Beam xT Nova NanoLab 600i FEGSEM/FIB microscope. This was achieved using a focused Ga<sup>+</sup> ion beam of 280 nA accelerated by an electric field of 30 kV. At each increment the stress relaxation was recorded by FEGSEM image taken normal to the surface at a resolution of  $1024 \times 884$  pixels taken with magnification of  $10,000 \times$ . A focused electron beam of 0.40 nA was accelerated by an electric field of 5 kV and secondary electrons were detected using Everhart Thornley Detector (ETD). Each FEGSEM image was an average from 8 scans with a dwell time of the electron beam of 3  $\mu$ s.

<sup>&</sup>lt;sup>†</sup> purity better then 99.9% by weight

**Digital Image Correlation Analysis.** The surface displacements due to the stress relaxations are mapped from FEGSEM images at each increment using LaVision DaVis 7.2 DIC software (see Figure 2a). The DIC analysis is undertaken at locations corresponding to the positions of strain gauges of a virtual strain-gauge rosette of  $r_a/r = 0.50$ , where  $r_a$  is the radius of the hole and r is the radius of the strain gauge rosette, see Figs 1a and 2b. During the analysis, images are divided into smaller sub-regions (patches), which are individually correlated [16]. Before analyzing the microhole milling experiment, the best vector calculation parameters (VCP) were determined from two FEGSEM images captured before hole milling as described elsewhere [15]. Estimated DIC analysis accuracy is presented in Table 1. The random error is determined as the standard deviation of strain measurement determined from two FEGSEM images captured before the hole milling. Whereas the systematic error is the scatter in strain measurement using different VCPs:  $32 \times 32$  pixels overlapped by 25 and 50 %, and  $64 \times 64$  pixels overlapped by 50 and 75%.

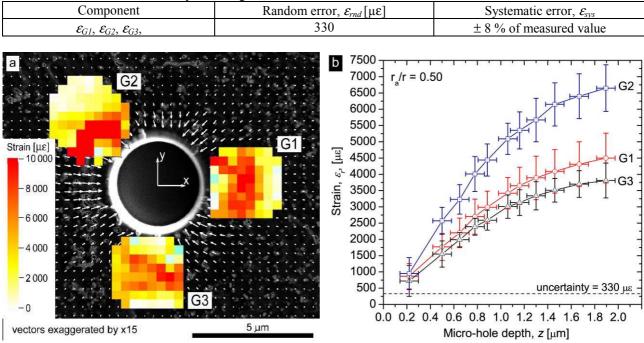


Table 1. Estimated DIC uncertainty for a single vector.

Figure 2. Digital image correlation analysis results for the final increment,  $z = 1.8 \pm 0.07 \,\mu\text{m}$ : (a) 2-D displacement vector field (vectors are magnified ×15) with the radial strains measured at the locations corresponding to a virtual strain-gauge rosette of  $r_a/r = 0.50$  superimposed; (b) average radial strains, G1, G2 and G3, vs. hole depth, z.

**The Integral Method.** To infer the residual stress profiles ( $\sigma_x$ ,  $\sigma_y$  and  $\tau_{xy}$ ) with depth we used directly the Integral Method proposed by Schajer [4, 5]. In essence the non-uniform stress profiles can be calculated using three pseudo-inversion equations in matrix notation

$$[P] = E/(1+\nu)[\overline{a}^T \overline{a}]^{-1}[\overline{a}]^T[p], \qquad (1)$$

$$[Q] = E[b^T b]^{-1}[b]^{t}[q],$$
(2)

$$[T] = E[b^T b]^{-1}[b]^{t}[t],$$
(3)

where  $E = 95 \pm 5$  GPa, and v = 0.37 [17];  $[\overline{a}]$  and  $[\overline{b}]$  are lower triangular matrices of coefficients corresponding to the cumulative strain relaxation functions for hole drilling into a equibiaxial and pure shear stress field, respectively. We assembled these matrices using the bivariate interpolation function and tabulated cumulative strain relaxation functions from [5]. The transformed stress variables (the column matrices *P*, *Q* and *T*) in Eqs. (1) – (3) which are acting at corresponding hole-depths in a plane parallel to the specimen surface are related to the Cartesian stress components as

$$[P] = \left[ \left( \sigma_y + \sigma_x \right) / 2 \right], \tag{4}$$

$$[Q] = [(\sigma_y - \sigma_x)/2],$$

$$[T] = [\tau_{xy}]$$
(5)
(6)

And the three strain relaxations measured at each hole-depth (the column matrices p, q and t) in Eqs. (1) – (3) are expressed in terms of transformed strain variables:  $[p] = [(\varepsilon_{G3} + \varepsilon_{G1})/2], [q] = [(\varepsilon_{G3} - \varepsilon_{G1})/2]$  and  $[t] = [(\varepsilon_{G1} + \varepsilon_{G3} - 2\varepsilon_{G2})/2]$ . The Cartesian stress components can be calculated from Eqs. (4) – (6)

**Stabilisation of Reconstruction Algorithm.** The pseudo-inversion algorithms, Eqs. (1) - (3), yield stable residual stress solutions if the entries of coefficients matrices  $[\overline{a}]$  and  $[\overline{b}]$  are of the same order of magnitude. However, the micro-hole milling process produces relatively small matrix entries in the diagonal bands of the coefficient matrices. Thus, Eqs. (1) - (3), become numerically ill-conditioned leading to unstable residual stress solutions. In practice this results in large oscillations of the residual stress solution with depth (see Fig. 3a). The problem of the ill-conditioned incremental calibration function matrices has been widely investigated [18]. In essence, the schemes proposed to counter this are based on careful selection of the hole-depths at which the residual stress solutions we used the Tikhonov regularisation scheme proposed by Tjhung & Li [7]. This scheme is significantly less sensitive to the depth increments chosen to back-calculate the residual stress profiles. We regularised Eqs. (1) - (3) into following form

$$[P_{\alpha}] = E/(1+\nu)[\alpha H_2^T H_2 + \overline{a}^T \overline{a}]^{-1}[\overline{a}]^T[p], \qquad (9)$$

$$[Q_{\alpha}] = E \left[ \alpha H_2^T H_2 + \overline{b}^T \overline{b} \right]^{-1} [\overline{b}]^T [q], \qquad (10)$$

$$[T_{\alpha}] = E[\alpha H_2^T H_2 + \overline{b}^T \overline{b}]^{-1} [\overline{b}]^T [t], \qquad (11)$$

where  $\alpha$  is the regularisation parameter and  $H_2$  is the second difference matrix operator. Within the adopted regularisation scheme we select the regularisation parameter basing on an estimate  $\delta$  of the error in the measured data, e.g. [p]. The parameter  $\alpha$  is chosen *a posteriori* in such way that the Euclidean norm of regularised solution discrepancy, e.g.  $\|(1+\nu)/E \cdot [\overline{\alpha}] P_{\alpha}] - [p]\|$  is equal to  $\delta$  the details are presented elsewhere [7]. The discrepancy in the measured displacements  $\delta_{est} = \|[\varepsilon_{rdn}] + [\varepsilon_{sys}]\|$ , the least-squares solution discrepancy  $\delta_0 = \|(1+\nu)/E \cdot [\overline{\alpha}] P_{\alpha}] - [p]\|$ , and the discrepancy after regularization  $\delta$  are shown in Table 2.

Table 2. The discrepancy for the measurement after regularisation

$\delta_{est} \left[ \mu \epsilon \right]$	$\delta_0 \left[ \mu \epsilon  ight]$	$\delta[\mu arepsilon]$
818	719	963

**Stress Calculation Error.** Several sources of measurement error arise leading to errors of different types [19]. For the IµHM method the errors originate from five main sources: (a) strain measurement errors, which include DIC calculation errors, material redeposition and additional residual stresses induced by Ga<sup>+</sup> ions implantation; (b) hole depth measurement errors, which include non-flatness of the bottom of the hole; (c) hole diameter measurement errors, which include tapering of the hole and deviation from roundness; (d) incorrect material constants; (e) hole eccentricity, which include possible focused ion beam drifts and the effects of possible eccentricity of DIC strain-gauge rosette from the centre of the micro-hole. In this study, following the argument in [19], we include the source (a) where the strain perturbations, e.g. [ $\delta p$ ] (the random error and the systematic error) result in calculated residual stress perturbation, e.g. [ $\delta P$ ], in Eqs. (1) – (3) and Eqs. (9) – (11).

Application of the IµHM method. Figures 3a and b shows the local in-plane residual stress profiles within the immediate vicinity of the surface of the S<sup>2</sup>PD treated Zr<sub>50</sub>Cu<sub>40</sub>Al<sub>10</sub> bulk metallic glass as a function of depth. The same sample has been studied previously over a larger depth range in [15]. Since we used a relatively large number of data points, the matrices  $[\overline{a}]$  and  $|\overline{b}|$  in Eqs. (1) -(3) are ill-conditioned, which result in large oscillations of the residual stress solution with depth and extremely large uncertainty levels, in Fig. 3a. The regularization procedure has effectively reduced the oscillations of the residual stress solution, simultaneously keeping the uncertainties at acceptable level, in Fig. 3b. Our results indicate that compressive residual stress component,  $\sigma_x$ , in the longitudinal direction of the sample (see Figure 1c) appears to be somewhat higher (<15%) than the stress component,  $\sigma_{v}$ , in the transverse direction. This difference may arise as a result geometry of the peened bar. There is some evidence of shear stresses (~230 MPa) indicating that the principal stresses lie at around 20° to the specimen length. The longitudinal stress averages to -920 MPa over the evaluation depth (1.8  $\mu$ m) and compares to -650 MPa obtained using the FIB microslotting method to a depth of 4.1 µm [15]. Some scatter in the data could arise from material redeposition in the vicinity of the micro-hole, which is more intense than for FIB microslotting method. The virtual strain gauge rosette method uses the displacement vectors only within 3 patches; we have found that this method tends to overestimate by about 10% the inferred residual stress profiles when compared with the quasi full-field method that uses all the vectors in an annulus around the hole [20].

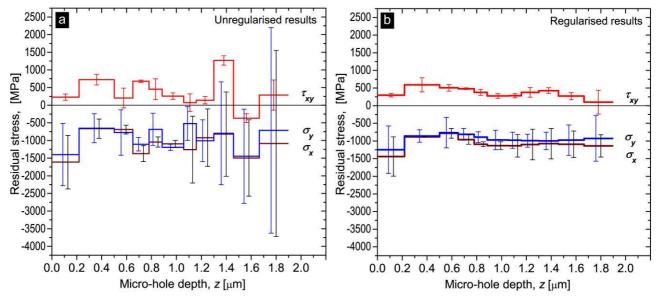


Figure 3. Inferred in-plane residual stresses profiles as a function of depth from the deformed surface: (a) unregularised stress components  $\sigma_x$ ,  $\sigma_y$  and  $\tau_{xy}$ ; (b) regularised stress components  $\sigma_x$ ,  $\sigma_y$  and  $\tau_{xy}$ .

**Conclusions.** In summary, this short paper presents a new method based on the integral method for mapping in-plane residual or applied stresses as a function of depth at the micron-scale laterally and sub-micron scale depth-wise. Instability problems associated with the Integral Method, when small increments of hole-depth are selected near or far from the surface were minimised by application of a Tikhonov regularization scheme [7]. The results obtained by the new method reasonably agree with the results inferred by other relaxation methods [15]. The potential applications of this technique are wide-ranging including stresses in amorphous thin films, MEMS components and devices, organic electronic devices, nanostructured materials, etc. Though applicable to crystalline materials, for amorphous materials our micro-hole milling method has few competitors.

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